

UNITED STATES DEPARTMENT OF COMME

Pat nt and Trademark Offic

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APPLICATION NO.	FILING DATE	FIRST NAMED II	NVENTOR		ATTORNEY DOCKET NO.	
09/652,968	08/31/00	AGARWAL.		V .	98-0616.12	— ⊁
-		and the second s	7		EXAMINER	
CHARLES B BR	ANTLEY II	MMC2/0828	•	DIAZ,J		
MICRON TECHN	IOLOGY INC		[ART UNIT	PAPER NUMBER	
3000 S FEDER 30ISE ID 837		_ STUP 525		2815		
				DATE MAILE): 08/28/01	•

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

· · · · · · · · · · · · · · · · · · ·		Application No.	Applicant(s)
Office Action Summary		09/652,968	AGARWAL, VISHNU K.
		Examiner	Art Unit
		José R. Díaz	2815
Period fo	The MAILING DATE of this communication app r Reply	pears on the cover sheet wi	th the correspondence address
THE N - Exter after - If the - If NO - Failu	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. Insions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. Period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period for the to reply within the set or extended period for reply will, by statute eply received by the Office later than three months after the mailing in patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a re y within the statutory minimum of thirt will apply and will expire SIX (6) MON	eply be timely filed by (30) days will be considered timely. ITHS from the mailing date of this communication. ANDONED (35 U.S.C. § 133).
1)⊠	Responsive to communication(s) filed on 19.		
2a)⊠		nis action is non-final.	
3)□	Since this application is in condition for allow closed in accordance with the practice under	ance except for formal ma Ex parte Quayle, 1935 C.	tters, prosecution as to the ments is D. 11, 453 O.G. 213.
Disposit	ion of Claims		
4)🖂	Claim(s) 43,44,76 and 77 is/are pending in th	e application.	
	4a) Of the above claim(s) is/are withdra	wn from consideration.	
5)□	Claim(s) is/are allowed.		
6)⊠	Claim(s) 43,44,76 and 77 is/are rejected.		
7)	Claim(s) is/are objected to.		
8)□	Claim(s) are subject to restriction and/o	or election requirement.	
Applicat	ion Papers		
9)[The specification is objected to by the Examine	er.	
10)	The drawing(s) filed on is/are: a) ☐ acce	epted or b) objected to by	the Examiner.
	Applicant may not request that any objection to the	ne drawing(s) be held in abey	rance. See 37 CFR 1.85(a).
11)	The proposed drawing correction filed on	_ is: a)□ approved b)□ (disapproved by the Examiner.
	If approved, corrected drawings are required in re	eply to this Office action.	
12)	The oath or declaration is objected to by the E	xaminer.	
	under 35 U.S.C. §§ 119 and 120		
13)	Acknowledgment is made of a claim for foreig	n priority under 35 U.S.C.	§ 119(a)-(d) or (f).
1	☐ All b)☐ Some * c)☐ None of:		
	1. Certified copies of the priority documer	nts have been received.	
	2. Certified copies of the priority documer	nts have been received in A	Application No
	3. Copies of the certified copies of the pri application from the International B See the attached detailed Office action for a lis	ureau (PCT Rule 17.2(a)).	,
440	Acknowledgment is made of a claim for domes	tic priority under 35 U.S.C	, § 119(e) (to a provisional application).
	The translation of the foreign language p Acknowledgment is made of a claim for dome	rovisional application has l	been received.
		one burell's amen' an ever	
Attachme		4) 🗍 Interview	v Summary (PTO-413) Paper No(s).
2) Not	ice of References Cited (PTO-892) ice of Draftsperson's Patent Drawing Review (PTO-948) rmation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice o	f Informal Patent Application (PTO-152)

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DETAILED ACTION

Claim Rejections - 35 USC § 102

➤ The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.
- > Claims 76 and 77 are rejected under 35 U.S.C. 102(e) as being anticipated by Narwankar et al. (US Patent No. 6,204,203).

Regarding claims 76-77, Narwankar et al. teach a method of forming a metal oxide dielectric film (see columns 1-12) comprising the steps of: layering a first conductive material (206) (see Figure 2a); introducing NH₃ or N₂ gas (see col. 5, lines 1-3); releasing nitrogen from said gas with electromagnetic energy (see columns 5, lines 1-3); and layering a second conductive material (212) (see Figure 2e).

Claim Rejections - 35 USC § 103

- > The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- > Claims 43-44 rejected under 35 U.S.C. 103(a) as being unpatentable over Narwankar et al. (US Patent No. 6,204,203 B1).

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Regarding claims 43-44, Narwankar et al. teach a method of forming a metal oxide dielectric film (see columns 1-12) comprising the steps of: layering a first conductive material (206) (see Figure 2a); introducing N₂/H₂ gas (see col. 5, lines 13-16); releasing nitrogen by thermal annealing (see columns 5, lines 13-37); and layering a second conductive material (212) (see Figure 2e). Furthermore, Narwankar et al. acknowledge that other well known anneal apparatuses such as furnace maybe used to anneal substrate 200 (see col. 5, lines 30-33). Official Notice is taken with respect to the limitation of releasing nitrogen with electromagnetic energy (e.g. ultraviolet light) since it is well known in the art that irradiating ultraviolet radiation in presence of a nitrogen gas such as N₂/H₂ is a conventional annealing step in a nitridation process.

Response to Arguments

> Applicant's arguments with respect to claims 43-44 and 76-77 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

- > The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Yamazaki (US Patent 4,717,602) and Kooi (US Patent No. 3,649,886) disclose method for producing nitride layers.
- > Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, THIS ACTION IS MADE FINAL. § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

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A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Correspondence

Any inquiry concerning this communication or earlier communications from the examiner should be directed to José R. Díaz whose telephone number is (703) 308-6078. The examiner can normally be reached on 8:00 - 5:00 Monday through Fridays.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on (703) 308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

EDDIE LEE

SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800

JRD August 22, 2001



ADEMARA			
FORM: PTO-1449	U.S. DEPARTMENT OF COMMERCE	Atty Docket No:	Serial No:
(REV: 7-80)	PATENT AND TRADEMARK OFFICE	98-0616.12	09/652,968
	2 ND SUPPLEMENTAL	Applicant:	
INFORMATION D	SCLOSURE STATEMENT BY APPLICANT	Vishnu K. Agarwal	
		Filing Date:	Group:
(37 CFR 1.98(b))	(use several sheets if necessary)	8/31/00	2815

U.S. PATENT DOCUMENTS

Examiner		Document				
Initial		Number	Date	Name	Class	Subclass
_ D	AA	6,165,802	12/26/00	Cuchiaro et al.	438	3
(%)	AB	5,726,083	03/10/98	Takaishi	438	210
7	AC					
	AD					
	AE					
	AF					
	AG	<u> </u>	/			
	AH					
	AI					
	AJ					
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FOREIGN PATENT DOCUMENTS

Examiner	Docum					Trans	lation
Initial	Numb	oer Date	Country	Class	Subclass	Yes	No
	AL						
	AM						
	AN						
	AO						
	AP						
	AQ						

Initial OTHER ART (including author, title, date, pertinent pages, etc.) AR AS ΑT

Examiner:		Date Considered: 8/21/01
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Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through crisinot in conformance and not considered. Include copy of this form with next communication with applicant. EXAMINER: